

ReRAM: Emerging as the New Embedded NVM Standard

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ReRAM: A Cost-Effective NVM



Fab-friendly materials

No contamination risk, special handling, etc.

Using existing deposition techniques and tools

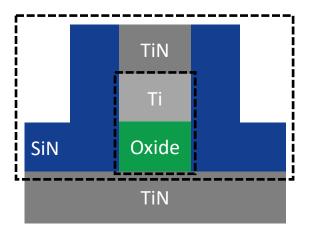
Easy to integrate into any CMOS fab

2-mask adder

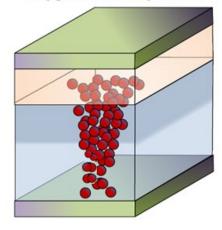
Very few added steps

BEOL technology

- Stack between any 2 metal layers
- No interference with FEOL
- Easy to scale from one process variation to another



Oxygen Vacancy Filament





State of Weebit ReRAM Today





Modules proven for toughest industrial & automotive mission profiles

- Retention at 175°C for automotive Grade 0 operation
- Completed AEC-Q100 qualification (150°C and 100K cycles)

Technology demonstrated on multiple process nodes

- From 130nm to 22nm, Al / Cu, 200mm / 300mm
- Analyzed & developed on 20+ PDKs; 130nm down to FinFET nodes

onsemi: Technology transfer underway

DB HiTek: Qualification starting; available for selected licensees

SkyWater: ReRAM module qualified and available for production

Jan 2025: License ReRAM to onsemi for its Treo™ platform









The ReRAM Difference



ReRAM is the Emerging Memory Best Positioned to Lead the Next NVM Wave

		eFlash	MRAM	PCM	ReRAM	Weebit is the	
Performance	Low power consumption					only independent provider of qualified ReRAM	
	Fast programming						
	High endurance						
Cost	Low cost to manufacture					We can license our technology to any fab*	
	Small die size						
Reliability	High-temp reliability						
	EMI immunity					We can customize Weebit ReRAM	
Scalability	Scalable to advanced nodes						
Integration	Ease of fab integration					per customer requirements	
Maturity	Mature technology					·	

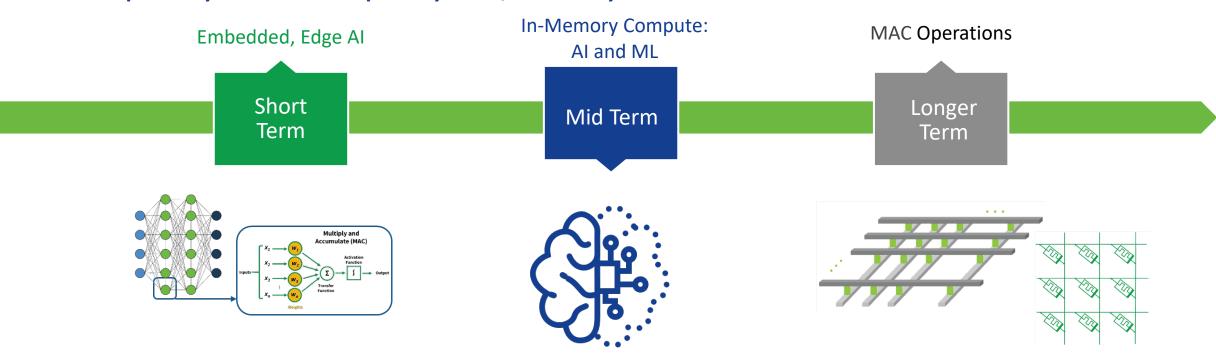


* Except US blacklisted

ReRAM for Al



ReRAM perfectly fits in brain inspired systems, in a timely manner:



ReRAM used as eNVM to store synaptic weights of the NN

Computing is done within the ReRAM array itself

Large ReRAM arrays for Vector Matrix Multiplication



Embedded NVM for Automotive





APPLICATIONS

Motor control, power management, microcontrollers NVM for code storage, data tables, data logging, configuration



TREND: SCALING TO ADVANCED NODES

Increasing number of semiconductors per car, performance requirements increasing; NVM must effectively scale <28nm



REQUIREMENTS

High-temp reliability (150°C), high endurance (100K), high density (2-32MB), EMI immunity, fast switching speed, secure



ALTERNATIVES

eFlash can no longer scale <28nm
MRAM (not immune to EMI, high complexity and cost)
ReRAM (EMI immunity, high-temp stability)

* Flash equivalent

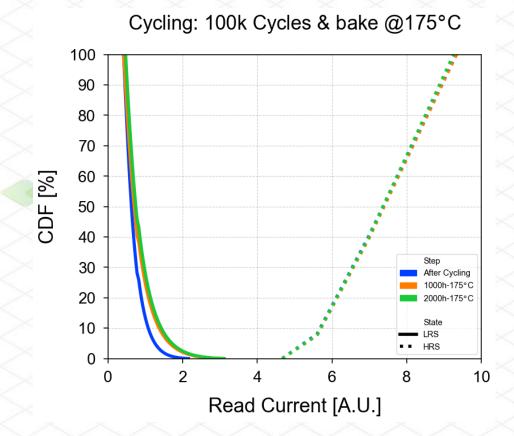
Weebit ReRAM is qualified for AEC-Q100 150°C operation for up to 100K endurance cycles



Addressing Demanding Automotive Mission Profiles



- Many automotive electronics operate in extreme thermal environments
 - Powertrain control units, Engine control units (ECUs), EV inverters, under-the-hood sensors, battery management systems (BMS)
- Weebit ReRAM high stability in 175°C retention
 - Supports AEC-Q100 Grade 0 and beyond
 - Aligns with next-gen vehicle requirements
- ELFR (Early Life Failure Rate) data:
 - Total samples (2,400) to claim very low failure rates confidently (often 0 DPPM to single-digit DPPM)
 - Lot 1 0/800
 - Lot 2 0/800
 - Lot 3 0/800
 - ✓ Covering lot-to-lot variations to show process consistency
 - ✓ Aligned with AEC-Q100 guidelines





Completed AEC-Q100 Operation Qualification for Automotive



Confirms quality & reliability of Weebit ReRAM for high-temp automotive applications



AEC-Q100: Key to Getting Designed Into Automotive MCUs & Other Components

- ❖ Demonstrated **stability at 150°C operation for up to 100K endurance cycles**, including cycling and post-cycling high-temp data retention at **175°C**
- ❖ Completed qual in SkyWater S130 using module with **1T1R cell architecture**
- ❖ Parameters of Weebit ReRAM align with automaker specifications

Test Name	Test Description	Stress Conditions	Sample Size	Results
NVCE	High Temp Cycling Endurance	100K cycles @ T _{Cycling} = 150°C	3 lots; 77 units from each lot	0 fails
PCHTDR	High Temp Post Cycle Data Retention	100K cycles @ $T_{Cycling} = 150$ °C $T_{Bake} = 175$ °C for 2000h	3 lots; 77 units from each lot	0 fails
HTOL	High Temperature Operating Life	Post 100K cycles @ T _{Cycling} = 150°C Read @ 150°C for 1000 hours	3 lots; 77 units from each lot	0 fails
ELFR	Early Life Failing Rate	48h Bake at 150°C	3 lots; 800 units from each lot	0 fails

Conclusions



- Weebit completed AEC-Q100 qualification targeting automotive applications
 - Retention up to 175°C
 - 100K endurance cycles
- Weebit ReRAM is in various engagement stages with commercial fabs
 - DB HiTek qualification starting
 - onsemi technology transfer underway
- Various AI architectures are being developed for edge applications
 - 2 live demonstrations available, running on Weebit ReRAM in silicon





Weebit: Leading Licensor of ReRAM IP



Leading developer of innovative next-generation memory technologies for the global semiconductor industry

We are enabling a leap forward in memory technology for a new era of connected devices



Founded: 2015

Located in Israel & France ASX: WBT



R&D partner

CEA-Leti, leading microelectronics research institute



Silicon-proven technology

Volume production expected 2026
Proven in multiple production-fab lots



World-leading team

>50 personnel (90% engineers/ scientists)



Signed multiple commercial deals

Engaged with most top-tier foundries, IDMs and customers



Qualified for 85°C, 125°C, 150°C

Fully qualified per JEDEC Fully qualified per AEC-Q100 150°C Available for chip designers



Financial strength

>A\$100m cash end of 2024 Well-funded going forward



Current business model

Product & IP licensing to semiconductor companies & fabs



Process nodes

130nm, 65nm, 28nm, 22nm and below Bulk, BCD, FD-SOI, FinFET





Thank You!

www.weebit-nano.com

